## NSN 5961-01-130-5193

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-130-5193 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect-dual gate **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 drain to source voltage and 55.0 drain to gate voltage **Current Rating Per Characteristic:** 30.00 milliamperes zero-gate-voltage source current megawatts **Power Rating Per Characteristic:** 0.15 watts small-signal input power, common-collector absolute **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**